- Contents -

■ General handling precautions1-2
■ Electrical & optical parameters & definitions
■ Package type & dimensions4-5
■ How to read the part number - Numbering5
■ Red laser - 635nm
1. SLD63518240 for Measuring instrument
2. SLD63518240C for Measuring instrument
3. SLD63518240J for Measuring Instrument8
4. SLD63518250 for Measuring instrument / Barcode Scanner
5. SLD63518260 for Measuring instrument / Barcode Scanner
6. SLD63518350 for Measuring instrument / Barcode Scanner11
■ Red laser - 650nm
7. SLD65018250ST for Bercode Scanner / Pointer
8. SLD65038250ST for Barcode Scanner / Pointer
9. SLD65018260 for Barcode Scanner / Sensor14
10. SLD65018271 for DVD-P / DVD-R
11. SLD65018271L for DVD-P / DVD-R
12. SLD65018271M for DVD-P / DVD-R17
13. SLD65018371 for DVD-Combo / Industrial Barcode Scanner
14. SLD65018871 for DVD-RW
■ Infrared laser - 780nm
15. SLD78018261 for CD-P / CD-R
16. SLD78018261F for CD-P / CD-R
17. SLD78018262C for LSU (Laser printer)
18. SLD78018271D for CD-P (Discrean)
19. SLD78018360P for LSU (Laser printer)24
20. SLD78018371 for CD-R / CD-P25
21. SLD78018971 for CD-RW26
III Book & Antin Book Management Annual
Red / Infra-Red Monolithic laser
22. 2 Beam laser for DVD-P / DVD-R
■ Packing spec
E Facility speci.
■ Labeling spec. 28

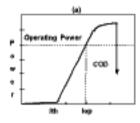
■ General handling precautions

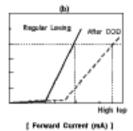
1. INTRODUCTION

Leser Diode (LD) is a semiconductor device with p-n junction which emit leser / strong conerancy / redistion by applying a current in forward direction. However, in difference from usually semiconductor diodes LD have the next peculiarities.

1.LD usually operates at operation current 20-40mA for a low power LD and 80-120mA for a high power LD and low applied forward voltage (usually -2V). But very important peculiarity of LD is high current densities (-2000-4000A/om*) during LD operation. Therefore, LD operation generates a significent heat thin active layer.

2.in normal operation mode LD has a relatively small volume for leser output power (3-7mW for low power LD and 25-220mW for high power LD). But they have a very high density of leser radiation in a active layer and on output minor facet (-1.0MWcm² and more). Therefore, there is a optical power limit caused by optical damage of output minor facet / COD (Catastropic Optical Damage) /.





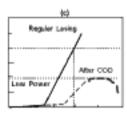
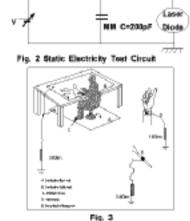


Fig. 1 COD (Catastropic Optical Damage)

Fig. 1 shows us typical CCO phenomenon of leser diode. When you operate LD after occurrence of COD, operating current at a specific power would be much higher than before COD -Fig.1(b). In the worst case, later power could not reach a required power due to COD -Fig.1(a). When you drive LD, please pay attention to LD operation under COD power level.

3.LD has a very quick electrical and light response (lower than a few nano-second and less). In connection with these features LD are extremely susceptible to damage caused by ourself surges, it must be stressed here that leven an instantaneous application extra pulse current cause a repid LD's deterioration. Whenever You handle LD, please pay strict attention to the following precautions.

2. ELECTROSTATIC SURGE PREVENTION.



It is necessary to setter that LD are even more sensitive to electrostatic discharge than Si-based semiconductor chips and require more careful preventive measures. COD also could be happened by small surge due to electrostatic discharge. Fig. 2 shows us a static electricity test circuit of Samsung. When shipping the lesser diodes, they would be inserted in artistatic bags to prevent electrostatic charging by transportation Example of a typical workbench for operation with Laser Diode Fig. 3:

- Ground work tables and floors using conductive table mate and floor mats;
- 2.Ground operators using conductive wrist bands;
- All used tools as well as soldering irons should be ground

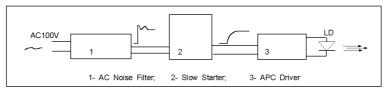
The grounding should be connected through a resistor of approximately $1 \text{N}\Omega$

3. PRECAUTIONS FOR CURRENT DRIVING CIRCUITS

1. While operating, LD can be easily damaged by surge currents which may occur during power on and off of the drive circuit or while adjusting the optical power output.

2.If possible, for standard testing process we recommend to use the special industrial laser diode current driver for example the Melles Griot current source 06 DLD 201 or other type.

3. When you use nonindustrial self designed drivers, please make it sure that the spike current generated in on-off switching of power supplies does not exceed the maximum LD operation current. It is recommended to insert an appropriate filter consisting of a appropriate CR circuit or other slow start circuit when chattering or overshoot shown in Fig. 4. Care must also be taken to prevent surge currents from entering the circuit from external sources. Use an AC noise filter.



Maximum
Power Rating

Output Laser Power

Power Power Rating

Pumping Pulse

Current

Fig. 5

Fia. 4

In pulse mode operation, overshoot in optical power output is sometimes observed.

In this case, try to suppress the overshoot or lower the overshoot power level below the maximum LD operation current shown in Fig.

4.Make all electrical connections secure. An open or short circuit while the LD is on, will result in deterioration. It is desirable to use chiefded earlier.

5.Use a reliable control for setting the operation current. Improper contacts may result in current surges.

6.While LD is powered up, don't touch probes from a oscilloscope or volt-meter against the circuit or LD terminals.

 $7.Don't\ CONNECT\ OR\ DISCONNECT\ the laser diode terminals while the POWER is ON.$

4. HEAT DIFFUSION PRECAUTIONS.

1.All main LD's parameters depend on a temperature. Because of LD in operation during generation of heat at the p-n junction/ active layer/ it is necessary provide a good heat conduction mechanism. Usually LD chip is mounted on a heat sink within the package to facilitate effective heat diffusion. Because the heat sink conducts the generated heat to the package flange, it is advisable LD to attach a heat radiator to the LD package flange for better heat diffusion. Thermal contact between the package flange and the heat radiator plate must be good. Furthermore heat diffusion also depends on the design of the radiator plate, i.e., shape, size and material. An appropriate design is required for each industrial application.

2.Ineffective heat diffusion can cause a positive feed back of driving current and limit the usability of the LD. Namely, high temperature of LD package reduces an optical output power below an expected level, which requires higher driving current to maintain the nominal output. As a result, this raises the temperature and requires more higher current. Thus excessive driving current can destroy LD.

5. ON THE SAFETY OF LASER LIGHT



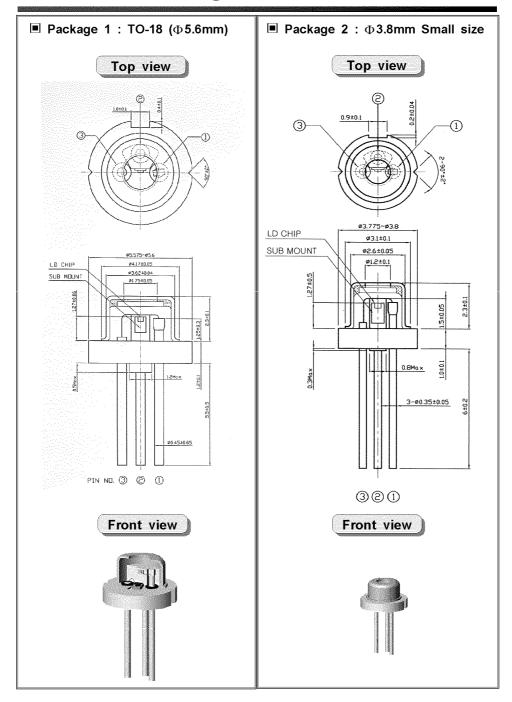
Avoid to look into the laser light directly or directly through an optical system. It is very **DANGEROUS!** Samsung red and IR laser diodes correspond to the class IIIb of the International Radiation Standard of the Laser Products.

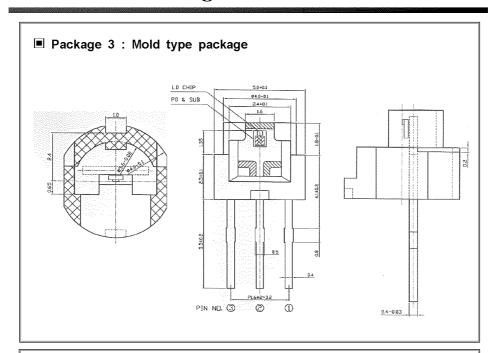
Although the typical optical output power of Samsung low power laser ranges from a several mW to 5mW, their power density can reach 1MW/cm². For observing laser beam safely, you always have to use safety goggles that block infrared rays.

■ Electrical & optical parameters & definitions

		Maximum allowable instantaneous light power in pulse or CW			
Output optical power	Pop	mode. Up to this output level there are no kinks in the Light-			
		Current curve.			
On a restimate assume that	la.	The forward current through the LD which necessary for the			
Operating current	lop	LD to produce its specified typical optical output power			
O4i	V	The forward voltage across the LD by forward operating			
Operating voltage	Vop	current			
Marialameth		The wavelength of the laser spectral line with the greatest			
Wavelength	λр	intensity			
		The value of the incremental change in laser beam power			
Watt-ampere / Slope / Efficiency	SE	for an incremental change in forward current above the			
		threshold current.			
Monitoring ourrent	lm	The monitoring photodiode current is proportional to LD laser			
Monitoring current	"""	output power/ at a specified reverse bias voltage			
Threshold current	lth	The forward current value at which the LD begins to produce			
Tillesiloid cultelli	laser output				
Laser beam divergency		The laser beam's full angular at the half-maximum intensity			
	points(FWHM), measured in horizontal plane /parallel to the				
in horizontal plane		LD p-n junction plane/			
Laser beam divergency		The laser beam's full angular at the half-maximum intensity			
in vertical plane	ө т	points(FWHN), measured in vertical plane			
iii verticai piane		/perpendicular to the LD p-n junction plane/			
LD reverse voltage	VR	Maximum admissible reverse bias voltage, which may be			
ED ICECISE VOIMIGE	VIX	applied to the LD without a damage			
PD bias voltage	VRp	Maximum admissible reverse bias voltage, which may be			
. = sas voiage	VICE	applied to the monitoring PD without a damage			
Operating temperature	Topr	Range of the case temperature within which LD may be			
Operating temperature	ТОРІ	safety stored			
Storage temperature	Tstg	Range of the ambient temperature within which LD may be			
otorage temperature	1319	safety stored			
Forward current	If	Current through the forward biased LD			
Forward bias voltage	Vf	Laser diode voltage by an applied forward bias			







■ How to read the part number - Numbering

EX.) SLD - 650 - 18 - 2 7 1 X

1

2

3

1)

6

7

① Samsung Laser Diode

② Wavelength : 635nm, 650nm, 780nm

③ Package type : 18 \Rightarrow TO-18 (5.6mm)

38 ⇒ Small package (3.8mm)

★ Suffix 'F' ⇒ Mold type package

4 Optical power : 2 \Rightarrow 5mW, 3 \Rightarrow 7mW, 8 \Rightarrow 50mW, 9 \Rightarrow 90mW

6 Pin configuration : 0 \Rightarrow LD anode, PD cathode, common

 $1 \Rightarrow LD$ anode, PD anode, common

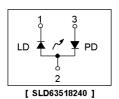
2 ⇒ LD cathode, PD anode, common

Suffix : Derivative parts

1. SLD63518240

■ Application : Measuring Instrument

■ Features



■ Absolute maximum ratings [$Tc = 25^{\circ}C$]

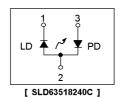
Parameter	Symbol	Value	Unit
Optical output power	Ро	7	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +40	С
Storage temperature	Tstg	- 40 ~ +85	r

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	5	-	mW
Threshold current	Ith	-	-	30	35	mA
Operating current	lop	Po = 5mW	-	38	40	mA
Operating voltage	Vop	Po = 5mW	-	2.2	2.7	٧
Monitor current	Im	Po = 5mW	0.01	0.04	0.1	mA
Lasing wavelength	λ	Po = 5mW	630	637	640	nm
	θ //	Po = 5mW	6	8	15	
Beam divergence	θ⊥	Po = 5mW	22	33	40	1
	Δθ //	Po = 5mW	-	-	± 1.5	degree
Beam angle accuracy	Δθ⊥	Po = 5mW	-	-	± 2.5	
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 5mW	-	-	± 60	μm
Differential efficiency	η	-	0.3	0.5	0.7	mW/mA
Astigmatism	As	Po = 5mW	-	-	-	μm

2. SLD63518240C

■ Application : Measuring Instrument

■ Features



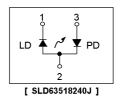
Parameter	Symbol	Value	Unit
Optical output power	Po	7	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +40	C
Storage temperature	Tstg	- 40 ~ +85	C

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	5	-	mW
Threshold current	lth	-	-	30	35	mA
Operating current	lop	Po = 5mW	-	33	36	mA
Operating voltage	Vop	Po = 5mW	-	2.2	2.7	V
Monitor current	lm	Po = 5mW	0.01	0.04	0.1	mA
Lasing wavelength	λ	Po = 5mW	630	637	640	nm
B "	θ //	Po = 5mW	6	8	15	
Beam divergence	θ ⊥	Po = 5mW	22	32	40	1.
	Δ θ //	Po = 5mW	-	-	± 1.5	degree
Beam angle accuracy	Δθ⊥	Po = 5mW	-	-	± 2.5	
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 5mW	-	-	± 60	μm
Differential efficiency	η	-	0.3	0.5	0.7	mW/mA
Astigmatism	As	Po = 5mW	-	-	-	μm

3. SLD63518240J

■ Application : Measuring Instrument

■ Features



\blacksquare Absolute maximum ratings [Tc = 25 $^{\circ}$ C]

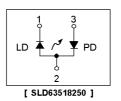
Parameter	Symbol	Value	Unit
Optical output power	Ро	7	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +40	$\mathcal L$
Storage temperature	Tstg	- 40 ~ +85	C

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	5	-	mW
Threshold current	Ith	-	-	30	35	mA
Operating current	lop	Po = 5mW	-	43	48	mA
Operating voltage	Vop	Po = 5mW	-	2.3	2.7	V
Monitor current	Im	Po = 5mW	0.01	0.04	0.1	mA
Lasing wavelength	λ	Po = 5mW	630	637	640	nm
D	θ //	Po = 5mW	6	8	15	
Beam divergence	θ⊥	Po = 5mW	22	32	40] .
	Δ θ //	Po = 5mW	-	-	± 1.5	degree
Beam angle accuracy	Δθ⊥	Po = 5mW	-	-	± 2.5	
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 5mW	-	-	± 60	μm
Differential efficiency	η	-	0.3	0.5	0.7	mW/mA
Astigmatism	As	Po = 5mW	-	-	-	μm

4. SLD63518250

■ Application : Measuring Instrument, Barcode Scanner

■ Features



\blacksquare Absolute maximum ratings [Tc = 25 $^{\circ}$ C]

Parameter	Symbol	Value	Unit
Optical output power	Po	7	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +50	${\mathbb C}$
Storage temperature	Tstg	- 40 ~ +85	C

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	5	-	mW
Threshold current	lth	-	-	30	40	mA
Operating current	lop	Po = 5mW	-	40	52	mA
Operating voltage	Vop	Po = 5mW	-	2.2	2.7	V
Monitor current	Im	Po = 5mW	0.1	0.3	0.5	mA
Lasing wavelength	λ	Po = 5mW	630	637	640	nm
	θ //	Po = 5mW	6	8	10	
Beam divergence	θ⊥	Po = 5mw	30	33	40	1.
	Δθ //	Po = 5mW	-	-	± 2.0	degree
Beam angle accuracy	Δθ⊥	Po = 5mW	-	-	± 2.5	
Positional accuracy	ΔΧ,ΔΥ,ΔΖ	Po = 5mW	-	-	± 60	μm
Differential efficiency	η	-	0.4	0.6	0.8	mW/mA
Astigmatism	As	Po = 5mW	-	-	-	μm

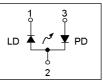
5. SLD63518260 - Preliminary

■ Application : Measuring Instrument, Barcode Scanner

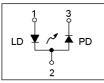
■ Features

• Lasing wavelength : $\lambda p = 635 nm$ • Optical output power : Po = 5mW (CW)
• Package type : TO -18 [Φ 5.6]
• Built-in photodiode for optical power monitoring

• InGaAIP laser with multi-quantum well structure



[SLD63518260]



[SLD63518262]

\blacksquare Absolute maximum ratings [Tc = 25 $^{\circ}$ C]

Parameter	Symbol	Value	Unit
Optical output power	Ро	7	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +60	$^{\circ}$
Storage temperature	Tstg	- 40 ~ +85	°C

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	5	-	mW
Threshold current	lth	-	-	30	40	mA
Operating current	lop	Po = 5mW	-	45	60	mA
Operating voltage	Vop	Po = 5mW	-	2.2	2.7	V
Monitor current	Im	Po = 5mW	0.1	0.2	0.5	mA
Lasing wavelength	λ	Po = 5mW	630	637	640	nm
	θ //	Po = 5mW	7	8.5	10	
Beam divergence	θ ⊥	Po = 5mW	22	33	40	
	Δ θ //	Po = 5mW	-	-	± 2.0	degree
Beam angle accuracy	Δθ⊥	Po = 5mW	-	-	± 2.5	1
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 5mW	-	-	± 60	μm
Differential efficiency	η	-	0.4	0.65	0.9	mW/mA
Astigmatism	As	Po = 5 mW	-	-	-	μm

6. SLD63518350 - Preliminary

■ Application : Measuring Instrument

■ Features

• Lasing wavelength : $\lambda p = 635 \text{nm}$ • Optical output power : Po = 7mW (CW) • Package type : TO-18 [Φ 5.6]

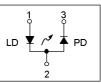
• Built-in photodiode for optical power monitoring

• High power laser

• InGaAIP laser with multi-quantum well structure

LD PD

[SLD63518350]



[SLD63518352]

■ Absolute maximum ratings [Tc = 25°C]

Parameter	Symbol	Value	Unit
Optical output power	Po	10	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +50	C
Storage temperature	Tstg	- 40 ~ +85	C

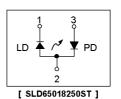
Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	7	-	mW
Threshold current	lth	-	-	30	40	mA
Operating current	lop	Po = 7mW	-	45	60	mA
Operating voltage	Vop	Po = 7mW	-	2.2	2.7	V
Monitor current	lm	Po = 7mW	0.1	0.2	0.5	mA
Lasing wavelength	λ	Po = 7mW	630	637	640	nm
	θ //	Po = 7mW	6	8.5	10	
Beam divergence	θ⊥	Po = 7mW	30	33	40	1.
	Δ θ //	Po = 7mW	-	-	± 2.0	degree
Beam angle accuracy	Δθ⊥	Po = 7mW	-	-	± 2.5	
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 7mW	-	-	± 60	μm
Differential efficiency	η	-	0.4	0.6	0.8	mW/mA
Astigmatism	As	Po = 7mW	-	-	-	μm

7. SLD65018250ST

■ Application : Barcode Scanner, Pointer

■ Features

 Lasing wavelength : λp = 650nm • Optical output power : Po = 5mW (CW) • Package type : TO-18 [₱ 5.6] • Built-in photodiode for optical power monitoring • InGaAIP laser with multi-quantum well structure



\blacksquare Absolute maximum ratings [Tc = 25 $^{\circ}$ C]

Parameter	Symbol	Value	Unit
Optical output power	Po	7	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +50	C
Storage temperature	Tstg	- 40 ~ +85	°C

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	5	-	mW
Threshold current	Ith	-	-	23	35	mA
Operating current	lop	Po = 5mW	-	30	40	mA
Operating voltage	Vop	Po = 5mW	-	2.2	2.6	V
Monitor current	Im	Po = 5mW	0.1	0.2	0.5	mA
Lasing wavelength	λ	Po = 5mW	650	655	660	nm
	θ //	Po = 5mW	6	8	11	
Beam divergence	θ Τ	Po = 5mW	22	30	38	
	Δ θ //	Po = 5mW	-	-	± 2.0	degree
Beam angle accuracy	Δθ⊥	Po = 5mW	-	-	± 3.0	
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 5mW	-	-	± 60	μm
Differential efficiency	η	-	0.5	0.75	0.95	mW/mA
Astigmatism	As	Po = 5 mW	-	-	-	μm

[SLD65038250ST]

8. SLD65038250ST

■ Application : Barcode Scanner, Pointer

■ Features

• Lasing wavelength : $\lambda p = 650 nm$ • Optical output power : Po = 5mW (CW)

• Package type : Small Package [Φ 3.8] • Built-in photodiode for optical power monitoring

• Ultra small package

• InGaAIP laser with multi-quantum well structure

■ Absolute maximum ratings [$Tc = 25^{\circ}C$]

Parameter	Symbol	Value	Unit
Optical output power	Po	7	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +50	C
Storage temperature	Tstg	- 40 ~ +85	$\mathcal C$

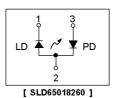
Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	5	-	mW
Threshold current	lth	-	-	30	35	mA
Operating current	lop	Po = 5mW	-	35	45	mA
Operating voltage	Vop	Po = 5mW	-	2.2	2.6	V
Monitor current	Im	Po = 5mW	0.08	0.2	0.5	mA
Lasing wavelength	λ	Po = 5mW	650	655	660	nm
5	θ //	Po = 5mW	6	9	11	
Beam divergence	ө т	Po = 5mW	22	30	38	1.
5	Δ θ //	Po = 5mW	-	-	± 2.0	degree
Beam angle accuracy	Δθ⊥	Po = 5mW	-	-	± 3.0	
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 5mW	-	-	± 60	μm
Differential efficiency	η	-	0.2	0.5	0.8	mW/mA
Astigmatism	As	Po = 5 mW	-	-	-	μm

9. SLD65018260

 \blacksquare Application : Barcode Scanner, Sensor

■ Features

• InGaAIP laser with multi-quantum well structure



■ Absolute maximum ratings [Tc = 25%]

Parameter	Symbol	Value	Unit
Optical output power	Ро	7	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +60	$^{\circ}$
Storage temperature	Tstg	- 40 ~ +85	C

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Ро	-	-	5	-	mW
Threshold current	lth	-	-	30	40	mA
Operating current	lop	Po = 5mW	-	40	50	mA
Operating voltage	Vop	Po = 5mW	-	2.2	2.6	V
Monitor current	Im	Po = 5mW	0.1	0.2	0.5	mA
Lasing wavelength	λ	Po = 5mW	648	651	654	nm
B	θ //	Po = 5mW	7	8	9.5	
Beam divergence	θ⊥	Po = 5mW	26	29	32	1
	Δ θ //	Po = 5mW	-	-	± 1.5	degree
Beam angle accuracy	Δθ⊥	Po = 5mW	-	-	± 2.5	
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 5mW	-	-	± 60	μm
Differential efficiency	η	-	0.4	0.65	0.9	mW/m/
Astigmatism	As	Po = 5 mW	-	8	10	μm

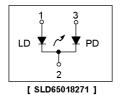
10. SLD65018271

■ Application : DVD-P, DVD-R

■ Features

• Lasing wavelength : λp = 650nm • Optical output power : Po = 5mW (CW) • Package type : TO -18 [Φ 5.6] • Built-in photodiodes for optical power monitoring

• InGaAIP laser with multi-quantum well structure



Parameter	Parameter Symbol Value		Unit
Optical output power	Po	7	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +70	C
Storage temperature	Tstg	- 40 ~ +85	C

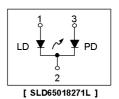
Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	5	-	mW
Threshold current	lth	-	-	30	40	mA
Operating current	lop	Po = 5mW	-	40	50	mA
Operating voltage	Vop	Po = 5mW	-	2.2	2.6	V
Monitor current	lm	Po = 5mW	0.1	0.2	0.4	mA
Lasing wavelength	λ	Po = 5mW	645	654	657	nm
D	θ //	Po = 5mW	7	8	10	
Beam divergence	θ⊥	Po = 5mW	25	28	32	
	Δ θ //	Po = 5mW	-	-	± 1.5	degree
Beam angle accuracy	Δθ⊥	Po = 5mW	-	-	± 2.5	
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 5mW	-	-	± 60	μm
Differential efficiency	η	-	0.4	0.65	0.9	mW/mA
Astigmatism	As	Po = 5 mW	-	-	12	μm

11. SLD65018271L

■ Application : DVD-P, DVD-R

■ Features

 $\begin{array}{lll} \bullet & \text{Lasing wavelength} & : \lambda p = 650 \text{nm} \\ \bullet & \text{Optical output power} & : \text{Po} = 5 \text{mW (CW)} \\ \bullet & \text{Package type} & : \text{TO-18} \left[\begin{array}{c} \Phi & 5.6 \end{array} \right] \\ \bullet & \text{Built-in photodiodes for optical power monitoring} \\ \bullet & \text{InGaAIP laser with multi-quantum well structure} \\ \end{array}$



\blacksquare Absolute maximum ratings [Tc = 25 $^{\circ}$ C]

Parameter	Symbol	Value	Unit
Optical output power	Ро	7	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +70	$\mathcal C$
Storage temperature	Tstg	- 40 ~ +85	C

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	5	-	mW
Threshold current	lth	-	-	30	35	mA
Operating current	lop	Po = 5mW	-	37	40	mA
Operating voltage	Vop	Po = 5mW	-	2.2	2.6	V
Monitor current	lm	Po = 5mW	0.1	0.2	0.3	mA
Lasing wavelength	λ	Po = 5mW	645	654	657	nm
	θ //	Po = 5mW	7	8	10	
Beam divergence	θ ⊥	Po = 5mW	25	28	33	1.
	Δθ //	Po = 5mW	-	-	± 1.5	degree
Beam angle accuracy	Δθ⊥	Po = 5mW	-	-	± 2.5	
Positional accuracy	ΔΧ,ΔΥ,ΔΖ	Po = 5mW	-	-	± 60	μm
Differential efficiency	η	-	0.5	0.7	0.9	mW/mA
Astigmatism	As	Po = 5 mW	-	-	12	μm

[SLD65018271M]

12. SLD65018271M

■ Application : DVD-P, DVD-R

■ Features

• Lasing wavelength : $\lambda p = 650 \text{nm}$ • Optical output power : Po = 5mW (CW) • Package type : TO-18 [Φ 5.6]

• Built-in photodiodes for optical power monitoring

• Multi-mode laser

• InGaAIP laser with multi-quantum well structure

■ Absolute maximum ratings [$Tc = 25^{\circ}C$]

Parameter	Symbol	Value	Unit
Optical output power	Po	7	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +70	C
Storage temperature	Tstg	- 40 ~ +85	С

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Ро	-	-	5	-	mW
Threshold current	lth	-	-	59	75	mA
Operating current	lop	Po = 5mW	-	72	90	mA
Operating voltage	Vop	Po = 5mW	-	2.2	2.6	V
Monitor current	lm	Po = 5mW	0.1	0.2	0.5	mA
Lasing wavelength	λ	Po = 5mW	645	658	660	nm
	θ //	Po = 5mW	7	8	12	
Beam divergence	θ ⊥	Po = 5mW	26	35	40	1.
	Δ θ //	Po = 5mW	-	-	± 1.5	degree
Beam angle accuracy	Δθ⊥	Po = 5mW	-	-	± 2.5	
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 5mW	-	-	± 60	μm
Differential efficiency	η	-	0.4	0.6	0.8	mW/mA
Astigmatism	As	Po = 5 mW	-	-	15	μm

13. SLD65018371

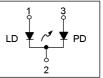
■ Application : DVD-Combo, Industrial barcode scanner

■ Features

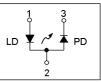
• Lasing wavelength : $\lambda p = 650 \text{nm}$ • Optical output power : Po = 7mW (CW) • Package type : TO -18 [Φ 5.6] • Built-in photodiode for optical power monitoring

High power laser

• InGaAIP laser with multi-quantum well structure



[SLD65018371]



[SLD65018372]

■ Absolute maximum ratings [$Tc = 25^{\circ}C$]

Parameter	Symbol	Value	Unit
Optical output power	Ро	10	mVV
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +70	C
Storage temperature	Tstg	- 40 ~ +85	C

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	7	-	mW
Threshold current	Ith	-	-	27	45	mA
Operating current	lop	Po = 7mW	-	37	43	mA
Operating voltage	Vop	Po = 7mW	-	2.25	2.6	V
Monitor current	Im	Po = 7mW	0.1	0.15	0.5	mA
Lasing wavelength	λ	Po = 7mW	645	655	660	nm
Б	θ //	Po = 7mW	7	9	10	
Beam divergence	θ⊥	Po = 7mW	24	26.5	33	1.
	Δ θ //	Po = 7mW	-	-	± 1.5	degree
Beam angle accuracy	Δθ⊥	Po = 7mW	-	-	± 2.5	-
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 7mW	-	-	± 60	μm
Differential efficiency	η	-	0.5	0.75	1.0	mW/mA
Astigmatism	As	Po = 7mW	-		15	μm

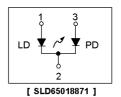
14. SLD65018871 - Preliminary

■ Application : DVD-RW, DVD-RAM

■ Features

• Lasing wavelength : $\lambda p = 650 \text{nm}$ • Optical output power : Po = 50mW (CW) • Package type : TO -18 [Φ 5.6] • Built-in photodiode for optical power monitoring

• High power laser



\blacksquare Absolute maximum ratings [Tc = 25 $^{\circ}$ C]

Parameter	Symbol	Value	Unit
Optical output power	Po	70	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +70	C
Storage temperature	Tstg	- 40 ~ +85	°C

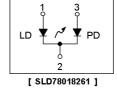
Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	50	-	mW
Threshold current	lth	-	-	35	55	mA
Operating current	lop	Po = 50mW	-	85	100	mA
Operating voltage	Vop	Po = 50mW	-	2.5	2.95	V
Monitor current	Im	Po = 50mW	-	-	-	mA
Lasing wavelength	λ	Po = 50mW	650	656	660	nm
	θ //	Po = 50mW	6	8.5	10	
Beam divergence	θ ⊥	Po = 50mW	19	22	25	1
	Δ θ //	Po = 50mW	-	-	± 2.0	degree
Beam angle accuracy	Δθ⊥	Po = 50mW	-	-	± 3.0	1
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 50mW	-	-	-	μm
Differential efficiency	η	-	0.8	1.0	-	mW/mA
Astigmatism	As	Po = 50mW	-	-	-	μm

15. SLD78018261

■ Application : CD-P, CD-R

■ Features

• Lasing wavelength : $\lambda p = 780 \text{nm}$ • Optical output power : Po = 3mW (CW)
• Package type : TO - 18 [Φ 5.6]
• Built-in photodiode for optical power monitoring
• AlGaAs laser with multi-quantum well structure



Parameter	Symbol	Value	Unit
Optical output power	Ро	5	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +70	C
Storage temperature	Tstg	- 40 ~ +85	C

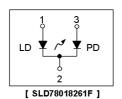
Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	<u> </u>	-	3	-	mW
Threshold current	Ith	-	-	40	50	mA
Operating current	lop	Po = 3mW	-	46	55	mA
Operating voltage	Vop	Po = 3mW	-	1.9	2.3	V
Monitor current	Im	Po = 3mW	0.1	0.2	0.5	mA
Lasing wavelength	λ	Po = 3mW	770	788	810	nm
	θ //	Po = 3mW	10	12.5	14	
Beam divergence	θ ⊥	Po = 3mW	20	36	40	1.
	Δθ //	Po = 3mW	-	-	± 1.5	degree
Beam angle accuracy	Δθ⊥	Po = 3mW	-	-	± 3.0	
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 3mW	-	-	± 60	μm
Differential efficiency	η	-	0.2	0.4	0.6	mW/m/
Astigmatism	As	Po = 3mW	-	-	-	μm

16. SLD78018261F

■ Application : CD-P

■ Features

Lasing wavelength : \(\lambda \) = 780nm
 Optical output power : Po = 3mW (CW)
 Package type : Plastic mold Package
 Built-in photodiodes for optical power monitoring
 AlGaAs laser with multi-quantum well structure



\blacksquare Absolute maximum ratings [Tc = 25 $^{\circ}$ C]

Parameter	Symbol	Value	Unit
Optical output power	Po	5	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +70	°C
Storage temperature	Tstg	- 40 ~ +85	C

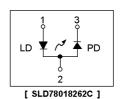
Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	3	-	mW
Threshold current	lth	-	-	40	50	mA
Operating current	lop	Po = 3mW	-	1.9	2.3	mA
Operating voltage	Vop	Po = 3mW	0.1	0.2	0.5	V
Monitor current	Im	Po = 3mW	770	785	810	mA
Lasing wavelength	λ	Po = 3mW	9	12	14	nm
- ·	θ //	Po = 3mW	20	35	40	
Beam divergence	θ⊥	Po = 3mW	-	-	± 1.5	1
	Δ θ //	Po = 3mW	-	-	± 3.0	degree
Beam angle accuracy	Δθ⊥	Po = 3mW	-	-	± 60	
Positional accuracy	ΔΧ,ΔΥ,ΔΖ	Po = 3mW	0.2	0.35	0.6	μm
Differential efficiency	η	-	-	-	-	mW/mA
Astigmatism	As	Po = 3mW	-	-	-	μm

17. SLD78018262C

■ Application : LSU (Laser printer)

■ Features

• Lasing wavelength : $\lambda p = 780 \text{nm}$ • Optical output power : Po = 3mW (CW)
• Package type : TO-18 [Φ 5.6]
• Built-in photodiode for optical power monitoring
• AlGaAs laser with multi-quantum well structure



Parameter	Symbol	Value	Unit
Optical output power	Ро	5	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +60	$^{\circ}$
Storage temperature	Tstg	- 40 ~ +85	C

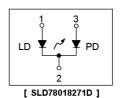
Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	3	_	mW
Threshold current	lth	-	-	40	50	mA
Operating current	lop	Po = 3mW	-	45	55	mA
Operating voltage	Vop	Po = 3mW	-	1.9	2.3	V
Monitor current	lm	Po = 3mW	0.15	0.2	0.47	mA
Lasing wavelength	λ	Po = 3mW	770	787	810	nm
	θ //	Po = 3mW	10	12.5	14	
Beam divergence	θ⊥	Po = 3mW	30	36	40	1.
	Δ θ //	Po = 3mW	-	-	± 1.5	degree
Beam angle accuracy	Δθ⊥	Po = 3mW	-	-	± 2.5	
Positional accuracy	ΔΧ,ΔΥ,ΔΖ	Po = 3mW	-	-	± 60	μm
Differential efficiency	η	-	0.3	0.42	0.6	mW/mA
Astigmatism	As	Po = 3mW	-	-	-	μm

18. SLD78018271D

■ Application : Disk-man (CD-P)

■ Features

• Lasing wavelength : $\lambda p = 780 \text{nm}$ • Optical output power : Po = 3mW (CW)
• Package type : TO-18 [Φ 5.6]
• Built-in photodiode for optical power monitoring
• AlGaAs laser with multi-quantum well structure



\blacksquare Absolute maximum ratings [Tc = 25 $^{\circ}$ C]

Parameter	Symbol	Value	Unit
Optical output power	Po	4	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +70	\mathcal{C}
Storage temperature	Tstg	- 40 ~ +85	°C

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	3	-	mW
Threshold current	lth	-	-	23	25	mA
Operating current	lop	Po = 3mW	-	26	28	mA
Operating voltage	Vop	Po = 3mW	-	1.9	2.3	V
Monitor current	Im	Po = 3mW	0.1	0.2	0.6	mA
Lasing wavelength	λ	Po = 3mW	770	785	810	nm
D	θ //	Po = 3mW	7.5	9.8	15	
Beam divergence	ө ⊥	Po = 3mW	20	33	45	1.
	Δ θ //	Po = 3mW	-	-	± 1.5	degree
Beam angle accuracy	Δθ⊥	Po = 3mW	-	-	± 2.5	
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 3mW	-	-	± 60	μm
Differential efficiency	η	-	0.7	0.89	1.1	mW/mA
Astigmatism	As	Po = 3mW	-	-	-	μm

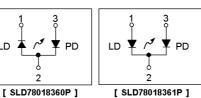
19. SLD78018360P

■ Application : LSU (Laser printer)

■ Features

 Lasing wavelength : λp = 780nm • Optical output power : Po = 5mW (CW) Package type : TO-18 [Ф 5.6] • Built-in photodiode for optical power monitoring

• AlGaAs laser with multi-quantum well structure





[SLD78018362P]

■ Absolute maximum ratings [Tc = 25°C]

Parameter	Symbol	Value	Unit
Optical output power	Po	7	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +60	$\mathcal L$
Storage temperature	Tstg	- 40 ~ +85	$^{\circ}$

Parameter	Symbol		Condition	Min.	Тур.	Max.	Unit	
Optical output power	Po		-	-	5	-	mW	
Threshold current	lth		-	-	30	45	mA	
Operating current	lop		Po = 5mW	-	45	60	mA	
Operating voltage	Vop	Po = 5mW		-	1.9	2.3	V	
Monitor current	lm	Po = 5mW		0.2	0.4	1.0	mA	
Lasing wavelength	λ		Po = 5mW	770	785	810	nm	
D	θ //		Po = 5mW	8	11	15		
Beam divergence	θ⊥		Po = 5mW	25	29	33	1.	
	Δθ //		Po = 5mW	-	-	± 2.0	degree	
Beam angle accuracy	Δθ⊥		Po = 5mW	-	-	± 2.5		
Positional accuracy	ΔΧ,ΔΥ,ΔΖ	Po = 5mW		-	-	± 60	μm	
Differential efficiency	η	-		0.2	0.4	0.6	mW/mA	
Astigmatism	(Pmax-Pmin) >	100	100Hz pulse rate at .9 &.1 duty cycle	-	5%	10%	μm	

20. SLD78018371

■ Application : CD-R, CD-P

■ Features

• Lasing wavelength : $\lambda p = 780 \text{nm}$ • Optical output power : Po = 7mW (CW) • Package type : TO-18 [Φ 5.6]

• Built-in photodiode for optical power monitoring

• High power laser

• AlGaAs laser with multi-quantum well structure

■ Absolute maximum ratings [$Tc = 25^{\circ}C$]

Parameter	Symbol	Value	Unit
Optical output power	Po	10	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +70	$^{\circ}$
Storage temperature	Tstg	- 40 ~ +85	C

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit	
Optical output power	Ро	_	-	7	-	mW	
Threshold current	lth	-	-	40	50	mA	
Operating current	lop	Po = 7mW	-	47	63	mA	
Operating voltage	Vop	Po = 7mW	-	2.0	2.3	V	
Monitor current	Im	Po = 7mW	0.1	0.2	0.5	mA	
Lasing wavelength	λ	Po = 7mW	780	786	810	nm	
	θ //	Po = 7mW	8	12	14		
Beam divergence	θ⊥	Po = 7mW	35	41	45		
	Δθ //	Po = 7mW	-	-	± 1.5	degree	
Beam angle accuracy	Δθ⊥	Po = 7mW	-	-	± 3.0	1	
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 7mW	-	-	± 60	μm	
Differential efficiency	η	-	0.6	0.86	1.1	mW/mA	
Astigmatism	As	Po = 7mW	-	-	15	μm	

[SLD78018971]

21. SLD78018971 - Preliminary

■ Application : CD-RW

■ Features

• Lasing wavelength : λp = 785nm

• Optical output power : Po = 100mW (CW), Po = 220mW (Pulse)

• Package type : TO-18 [Φ 5.6] • Built-in photodiode for optical power monitoring

• High power laser

\blacksquare Absolute maximum ratings [Tc = 25 $^{\circ}$ C]

Parameter	Symbol	Value	Unit
Optical output power	Po	100	mVV
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Tons	-10 ~ +65 (CW)	r
Operating temperature	Topr	-10 ~ +70 (Pulse)	
Storage temperature	Tstg	- 40 ~ +85	C

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Optical output power	Ро	-	-	90	-	mW
Threshold current	Ith	-	-	45	55	mA
Operating current	lop	Po = 90mW	-	130	150	mA
Operating voltage	Vop	Po = 90mW	-	2.3	2.5	V
Monitor current	Im	Po = 90mW	-	-	-	mA
Lasing wavelength	λ	Po = 90mW	780	784	788	nm
	θ //	Po = 90mW	7.5	9	10	
Beam divergence	θ⊥	Po = 90mW	14	17	18	
	Δ θ //	Po = 90mW	-	-	± 2.0	degree
Beam angle accuracy	Δθ⊥	Po = 90mW	-	-	± 2.5	
Positional accuracy	$\Delta X, \Delta Y, \Delta Z$	Po = 90mW	-	-	± 60	μm
Differential efficiency	η	-	0.8	1.0	1.3	mW/mA
Astigmatism	As	Po = 90mW	-	-	-	μm

22. 2 Beam Laser - Preliminary

■ Application : DVD-P, DVD-R

■ Features

Lasing wavelength : λp = 650nm (DVD), 780nm (CD)
 Optical output power : Po = 5mW (650nm), 7mW (780nm)

• Package type : TO-18 [Φ 5.6], 4 Pin • Built-in photodiode for optical power monitoring

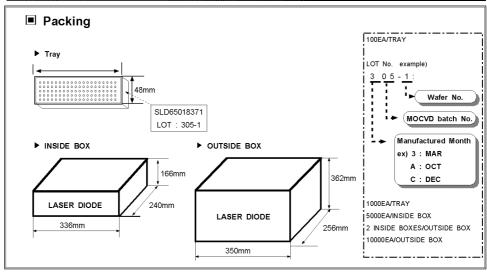
• 1 Chip 2 Beam laser : Monolithic

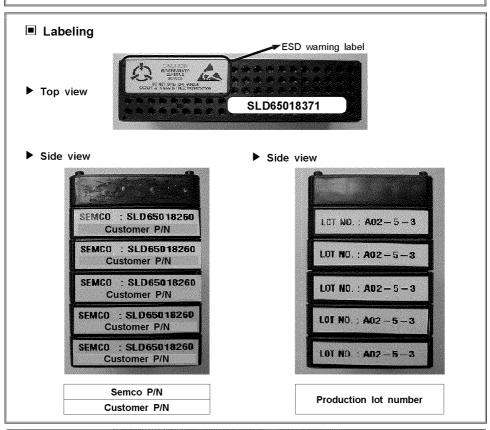
■ Absolute maximum ratings [$Tc = 25^{\circ}C$]

Parameter	Symbol	Value	Unit
Optical output power	Ро	7(650nm), 10(780nm)	mW
LD reverse voltage	VR	2	V
PD reverse voltage	VR	30	V
Operating temperature	Topr	-10 ~ +70	C
Storage temperature	Tstg	- 40 ~ +85	C

		A 1541	D\	/D (650n	ım)	C			
Parameter	Symbol	Condition	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Optical output power	Po	-	-	5	-	-	7	-	mW
Threshold current	lth	-	-	55	65	-	40	50	mA
Operating current	lop	Po = 5, 7mW	-	70	75	-	55	65	mA
Operating voltage	Vop	Po = 5, 7mW	-	2.2	2.6	-	1.9	2.5	V
Monitor current	Im	Po = 5, 7mW	0.1	0.2	0.5	0.12	0.3	0.6	mA
Lasing wavelength	λ	Po = 5, 7mW	645	655	660	770	785	800	nm
D	θ //	Po = 5, 7mW	7	8.5	11	10	11	15	
Beam divergence	θ⊥	Po = 5, 7mW	31	35	39	34	37	40	1
	Δθ //	Po = 5, 7mW	-	-	± 1.5	-	-	± 2.0	degree
Beam angle accuracy	Δθ⊥	Po = 5, 7mW	-	-	± 3.0	-	-	± 3.0	
Positional accuracy	ΔΧ,ΔΥ,ΔΖ	Po = 5, 7mW	-	-	± 60	-	-	± 60	μm
Beam Tolerance	-	-	-	-	-	-	-	-	μm
Differential efficiency	η	-	-	0.6	0.9	-	0.4	0.7	mW/mA
Astigmatism	As	Po = 5, 7mW	-	-	-	-	-	-	μm







Copyright © Each Manufacturing Company.

All Datasheets cannot be modified without permission.

This datasheet has been download from:

www.AllDataSheet.com

100% Free DataSheet Search Site.

Free Download.

No Register.

Fast Search System.

www.AllDataSheet.com